Video signal switcher BA7613N / BA7613F

The BA7613N and BA7613F are three-channel analog multiplexers with built-in mute, 6dB amplifier and 75Ω driver. The ICs designed for use in video cassette recorders, and feature a large dynamic range and wide operating frequency range. Sync-tip clamp inputs make this an ideal switch for video signals.

Applications

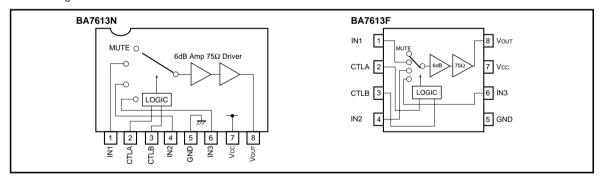
Video cassette recorders and televisions

Features

- 1) 3-input / 1-output switches.
- 2) Built-in 6dB amplifier and 75 Ω driver.
- 3) Built-in mute.
- 4) Sync-tip clamp inputs.
- 5) Wide operating supply voltage range (4.5V ~ 13.0V, BA7613N)
 - (4.5V ~ 9.5V, BA7613F).

- 6) Low power consumption (100mW Typ.).
- 7) Excellent frequency characteristics (10MHz, 0dB Typ.).
- 8) Wide dynamic range (3.5V_{P-P} Typ.).
- 9) Low interchannel crosstalk (-65dB Typ., f = 4.43MHz).

Block diagram



Truth table

| CTL A | CTL B | OUT | | |
|----------|----------|------|--|--|
| L (OPEN) | L (OPEN) | IN 1 | | |
| L (OPEN) | Н | IN 2 | | |
| Н | L (OPEN) | IN 3 | | |
| Н | Н | MUTE | | |

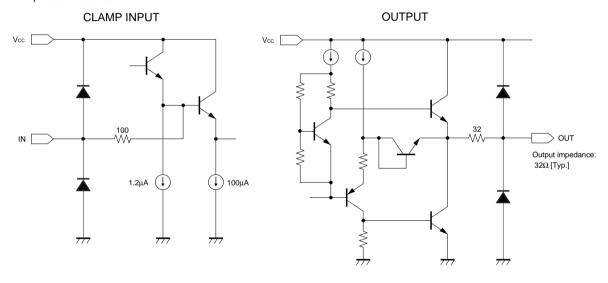


●Absolute maximum ratings (Ta = 25°C)

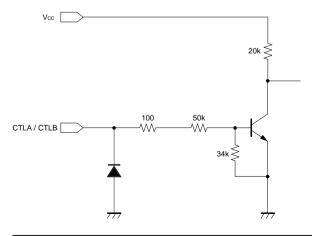
| Parameter | Symbol | Limits | Unit |
|-----------------------|--------|---------------------|------|
| Power supply voltage | Vcc | *113.5 / *210.0 | V |
| Power dissipation | Pd | *1900*3 / *2550*4 | mW |
| Operating temperature | Topr | − 25 ~ + 75 | °C |
| Storage temperature | Tstg | - 55 ~ + 125 | °C |

^{*1} BA7613N.

Equivalent circuits



CTLA / CTLB



^{*2} BA7613F.

^{*3} Reduced by 9.0mW for each increase in Ta of 1°C over 25°C.

^{*4} Reduced by 5.5mW for each increase in Ta of 1°C over 25°C.

●Electrical characteristics (unless otherwise noted, Ta = 25°V and Vcc = 5V)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|--------------------------|-------------------|-------|------|------|------------------|--|
| Operating voltage | Vcc | 4.5 | _ | 13.0 | V | BA7613F is Max.9.5V |
| Supply current | Icc | _ | 20.0 | 28.5 | mA | _ |
| Maximum output level | Vom | 3.0 | 3.5 | _ | V _{P-P} | f = 1kHz, THD = 0.5% |
| Voltage gain | G∨ | 5.5 | 6.0 | 6.5 | dB | f = 1MHz, Vin = 1.0VP-P |
| Interchannel crosstalk | Ст | _ | - 65 | _ | dB | f = 4.43MHz, V _{IN} = 1.0V _{P-P} |
| Frequency characteristic | Cf | - 3.0 | 0 | 1.0 | dB | f = 10MHz / 1MHz, Vin = 1.0V _{P-P} |
| CTL pin switch level A | V _{TH-A} | 1.0 | 2.0 | 3.0 | V | _ |
| CTL pin switch level B | Vтн-в | 1.0 | 2.0 | 3.0 | V | _ |

ONot designed for radiation resistance.

Measurement circuit

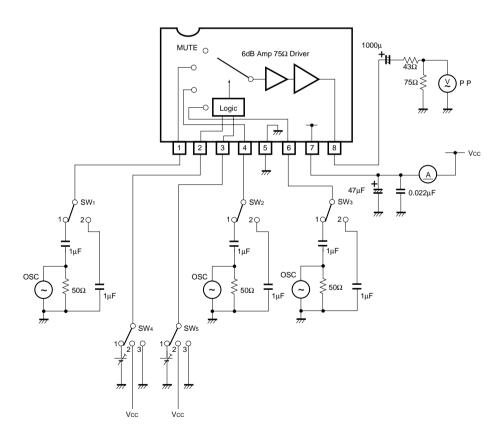


Fig. 1

Measurement conditions

| Parameter | | Oh. a.l | Switch settings | | | | | Measurement |
|---------------------------|-----------------|---------|-----------------|-----------------|-----|-----------------|-----------------|---|
| | | Symbol | SW ₁ | SW ₂ | SWз | SW ₄ | SW ₅ | method |
| Current dissipation | | Icc | 2 | 2 | 2 | 2 | 2 | Ammeter |
| Maximum | I _{N1} | Vom | 1 | 2 | 2 | 3 | 3 | f = 1kHz |
| output | l _{N2} | Vom | 2 | 1 | 2 | 3 | 2 | THD = 0.5% |
| level | lиз | Vom | 2 | 2 | 1 | 2 | 3 | *1 |
| Voltage gain | I _{N1} | Gv | 1 | 2 | 2 | 3 | 3 | f = 1MHz, |
| | I _{N2} | G∨ | 2 | 1 | 2 | 3 | 2 | V = 1V _{P-P} |
| | lnз | Gv | 2 | 2 | 1 | 2 | 3 | *2 |
| Interchannel crosstalk | In1→In2 | Ст | 1 | 2 | 2 | 3 | 2 | f = 4.43MHz, V = 1V _{P-P} *3 |
| | In1→In3 | Ст | 1 | 2 | 2 | 2 | 3 | |
| | In1→MUTE | Ст | 1 | 2 | 2 | 2 | 2 | |
| | In2→In3 | Ст | 2 | 1 | 2 | 2 | 3 | |
| | In2→MUTE | Ст | 2 | 1 | 2 | 2 | 2 | |
| | Iыз→МПТЕ | Ст | 2 | 2 | 1 | 2 | 2 | |
| Frequency characteristic | I _{N1} | Gf | 1 | 2 | 2 | 3 | 3 | f = 10MHz / f = 1MHz, |
| | I _{N2} | Gf | 2 | 1 | 2 | 3 | 2 | V = 1V _{P-P} |
| | Inз | Gf | 2 | 2 | 1 | 2 | 3 | *4 |
| CTL pin switching level | CTLA | Vтн | 2 | 2 | 1 | 1 | 3 | *5 |
| | CTLB | Vтн | 2 | 1 | 2 | 3 | 1 | |

^{*1:} Connect a distortion meter to the output, and input a f = 1kHz sine wave. Adjust the input level until the output distortion is 0.5%. This output voltage at this time multiplied by 2 is the maximum output level Vom (VP-P).

The frequency characteristic is given by Gf = 20 log (Vout (f = 10MHz) / Vout (f = 1MHz)).

The CTL pin switching level (VTH) is the CTL pin voltage at which the VouT level drops below 20mVP-P.

Electrical characteristic curves

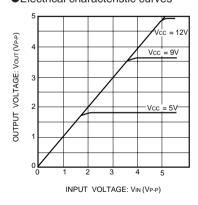


Fig. 2 Vin vs. Vout (f = 1kHz)

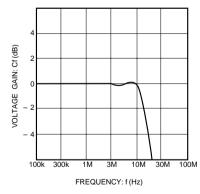


Fig. 3 Frequency characteristics

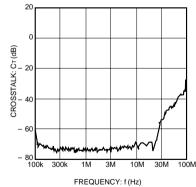


Fig. 4 Interchannel crosstalk

Operation notes

The output impedance is approximately 32Ω . Therefore, to ensure output matching, connect an external resistor of 43Ω .

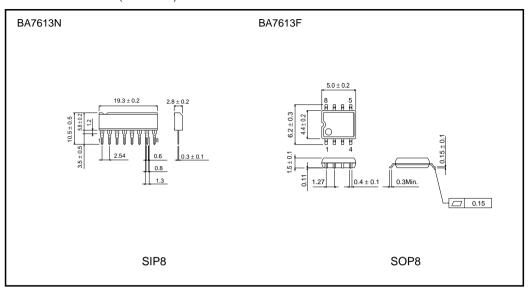
^{*2:} Input a 1VP-P, 1MHz sine wave. The voltage gain is given by GV = 20 log (VOUT / VIN) + 6.

^{*3:} Input a 1VP-P, 4.43MHz sine wave. The interchannel crosstalk is given by CT = 20 log (VouT / VIN).

^{*4:} Input 1VP-P, 1MHz and 10MHz sine waves.

^{*5:} Input a 1VP-P, 1MHz sine wave. Reduce the CTL pin voltage from Vcc.

●External dimensions (Units: mm)



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